

Power MOS V is a new generation of high voltage N-Channel enhancement mode power MOSFETs.

Manufacturers	Microchip Technology, Inc
Package/Case	97A/200V/MOS/1U
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for APT20M22JVR or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

Features

- Eliminating Parasitic Oscillation between Parallel MOSFETs
- High Frequency Resonant Half Bridge
- Improved Power MOSFETS Boost Efficiency IN A 3.5kw Single Phase PFC
- Introduction to MOSFETs
- Latest Technology PT IGBTs vs. Power MOSFETs
- Making Use of Gate Charge Information In MOSFET and IGBT Data Sheets
- Optimizing MOSFET and IGBT Gate Current to Minimize dv/dt Induced Failures in SMPS Circuits
- Turn Off Snubber Design for High Frequency Modules
- VDS(on) VCE(sat) Measurement



Related Products



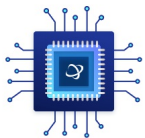
[APT5010JFLL](#)

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SOT227



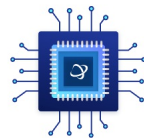
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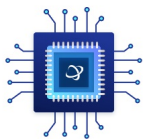
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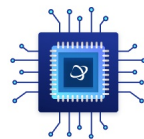
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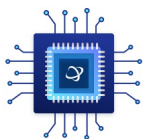
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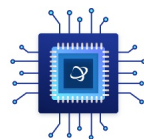
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